

Product data sheet

1. General description

Planar passivated high commutation three quadrant triac in a IITO3P package intended for use in circuits where high static and dynamic dV/dt and high dI/dt can occur. This "series BT" triac will commutate the full RMS current at the maximum rated junction temperature ($T_{j(max)} =$ 150 °C) without the aid of a snubber. It is used in applications where "high junction operating temperature capability" is required.

2. Features and benefits

- High current TRIAC
- 3Q technology for improved noise immunity
- · High commutation capability with maximum false trigger immunity
- High immunity to false turn-on by dV/dt
- High junction operating temperature capability (T_{i(max)} = 150 °C)
- High voltage capability
- Least sensitive gate for highest noise immunity
- Low thermal resistance
- Planar passivated for voltage ruggedness and reliability
- Triggering in three quadrants only
- Insulated tab rated at 2500Vrms

3. Applications

- Applications subject to high temperature (T_{i(max)} = 150 °C)
- High current / high surge applications
- High power / industrial controls e.g. heating, motors, lighting

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 105 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	-	-	45	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4; Fig. 5</u>	-	-	450	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	-	495	А
T _i	junction temperature		-	-	150	°C

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; Fig. 7	-	-	50	mA
		$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; <u>Fig. 7</u>	-	-	50	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>	-	-	50	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	80	mA
V _T	on-state voltage	I _T = 63.6 A; T _j = 25 °C; <u>Fig. 10</u>	-	-	1.7	V
Dynamic o	characteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	1000	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 20 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu\text{s}; \text{ (snubberless condition); gate open circuit}$	15	-	-	A/ms

5. Pinning information

Pinning infor	mation		
Symbol	Description	Simplified outline	Graphic symbol
T1	main terminal 1	\bigcirc	N
T2	main terminal 2	0	
G	gate		sym051
n.c.	mounting base; isolated		
	SymbolT1T2G	T1main terminal 1T2main terminal 2Ggate	SymbolDescriptionSimplified outlineT1main terminal 1Image: Constraint of the symbolImage: Constraint of the symbolT2main terminal 2Image: Constraint of the symbolImage: Constraint of the symbolGgateImage: Constraint of the symbolImage: Constraint of the symbol

6. Ordering information

Table 3. Ordering information								
Type number	Package	Orderable part number	Packing	Small packing	Package	Package		
	Name		method	quantity	version	issue date		
BTA445Z-800BT	IITO3P	BTA445Z-800BTQ	Tube	30	SOT1292	21-July-2017		

7. Marking

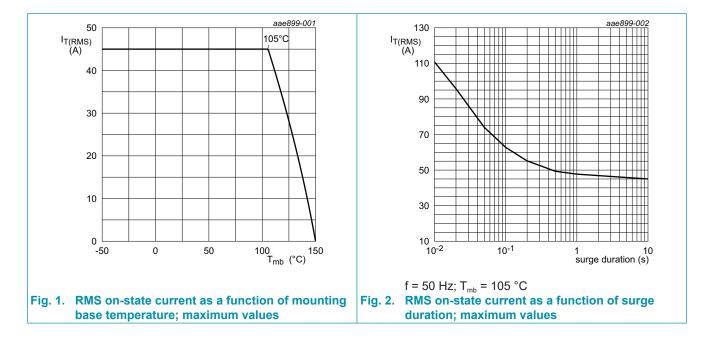
Table 4. Marking codes	
Type number	Marking code
BTA445Z-800BT	BTA445Z-800BT

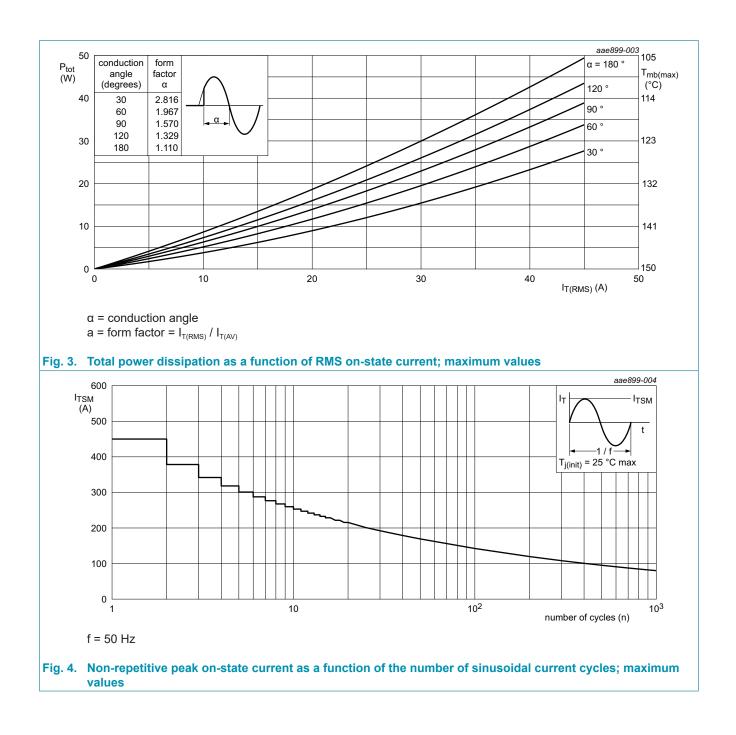
8. Limiting values

Table 5. Limiting values

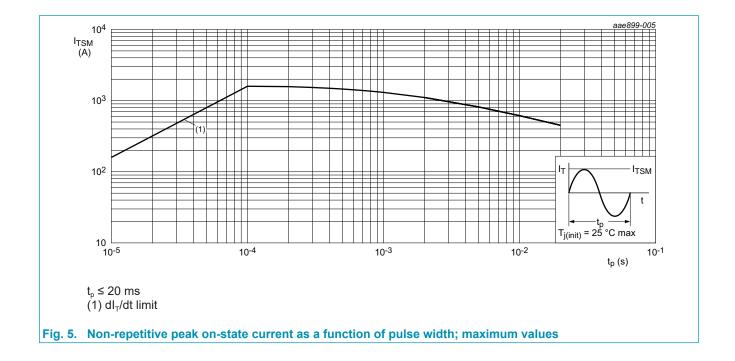
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Мах	Unit
V_{DRM}	repetitive peak off-state voltage		-	800	V
$\mathbf{I}_{\mathrm{T}(\mathrm{RMS})}$	RMS on-state current	full sine wave; T _{mb} ≤ 105 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	-	45	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig 4</u> ; <u>Fig 5</u>	-	450	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	495	А
l ² t	l ² t for fusing	t _p = 10 ms; sine-wave pulse	-	1012.5	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 100 mA	-	150	A/µs
I _{GM}	peak gate current	t _p = 20 μs	-	8	А
P_{GM}	peak gate power	t _p = 20 μs	-	40	W
$P_{\text{G}(\text{AV})}$	average gate power		-	1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C



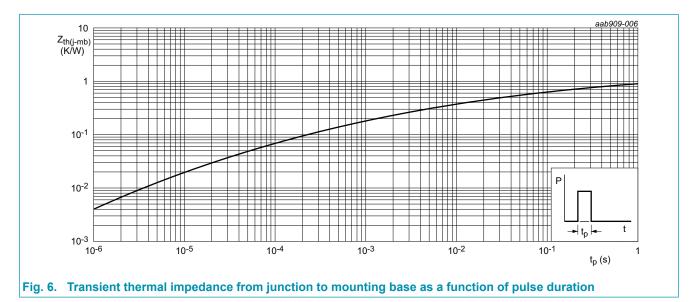


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9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<u>Fig 6</u>	-	-	0.9	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	50	-	K/W



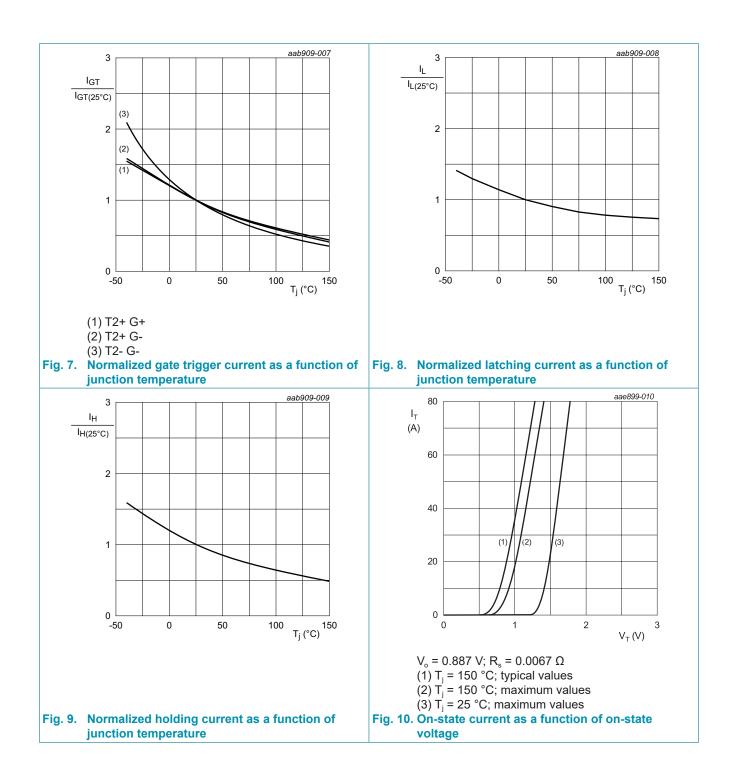
10. Isolation Characteristics

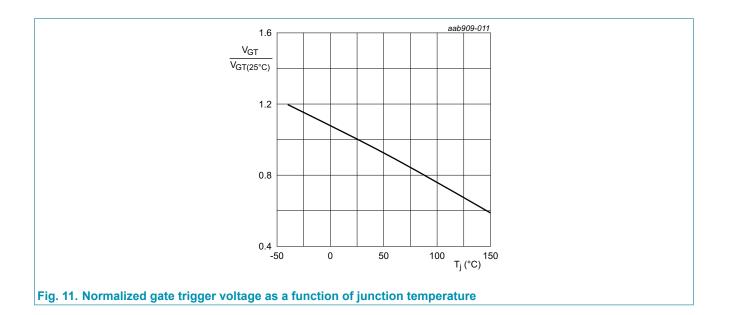
Table 7. Iso	Diation Characteristics	Conditions	Min	Тур	Max	Unit
V _{isol(RMS)}	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _{mb} = 25 °C	-	-	2500	V

11. Characteristics

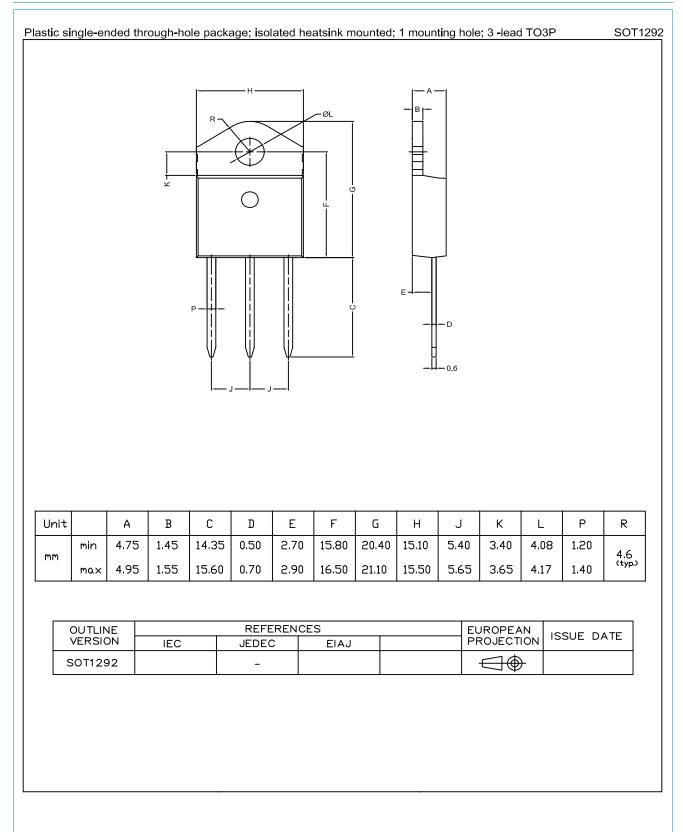
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	racteristics			1.01		
I _{GT}	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ $\text{T}_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 7}$	-	-	50	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; Fig. 7	-	-	50	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; Fig. 7	-	-	50	mA
I _L latchin	latching current	$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; Fig. 8	-	-	85	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; Fig. 8	-	-	160	mA
		V_{D} = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; Fig. 8	-	-	85	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	80	mA
V _T	on-state voltage	I _T = 63.6 A; T _j = 25 °C; <u>Fig. 10</u>	-	-	1.7	V
V _{GT}	gate trigger voltage	V _D = 12 V; T _j = 25 °C; <u>Fig. 11</u>	-	0.8	1.3	V
		V _D = 400 V; T _j = 150 °C	0.2	0.45	-	V
I _D	off-state current	V _D = 800 V; T _j = 25 °C	-	-	10	μA
		V _D = 800 V; T _j = 150 °C	-	-	2	mA
Dynamic	characteristics	· · · · ·				
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	1000	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 20 \text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu \text{s}; \text{ (snubberless condition); gate open circuit}$	15	-	-	A/ms

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12. Package outline



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13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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